



Northern Illinois
University

Towards Low-MTE Photocathodes in Accelerators

Oksana Chubenko

Department of Physics, Northern Illinois University

Introduction

AAC'26

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chubenko@niu.edu

High-quality electron beams =

- bright beams $B_{4D} \propto \frac{N_{bunch}}{\epsilon_x \epsilon_y} \propto \frac{(E_z)^k}{MTE}$

High-quality photocathodes =

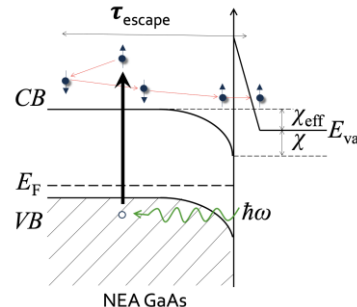
- low mean transverse energy, $MTE = \frac{m \langle v_{\perp}^2 \rangle}{2}$
MTE $\sim k_B T \sim 25$ meV at room temperature

Factors, limiting MTE:

- requirements of the high charge density
- disordered nature of photocathode materials
- surface roughness and work function variations

MTE $\sim$ few 100s meV

- high quantum efficiency, $QE = \frac{N_{e^-}}{N_{\gamma}}$
- prompt response time



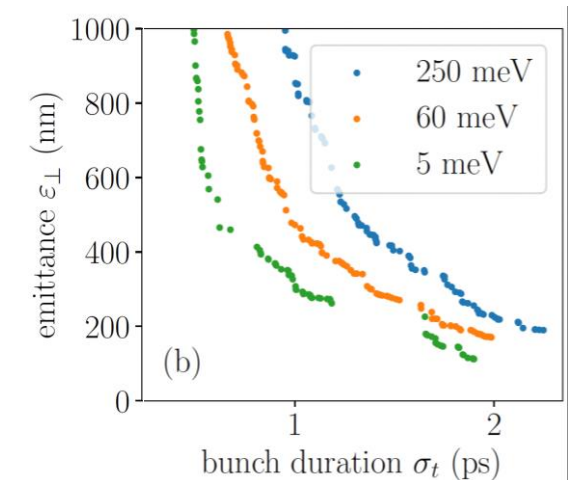
- robustness + long operational lifetime under realistic photoinjector conditions (5-100 MV/m to extract ~ 50 -1000 pC/mm² of charge densities/bunch)

High charge density regime:

$$N_{bunch} \propto \sigma_x \sigma_y (E_z)^k, \quad 1 \leq k \leq 2$$

$$\epsilon_{x,y} = \sigma_{x,y} \sqrt{MTE / m_e c^2}$$

Bazarov et al., Phys. Rev. Lett. **102**, 104801 (2009).



Frame, Marzouk, Chubenko et al, Instruments **7**, 48 (2023).

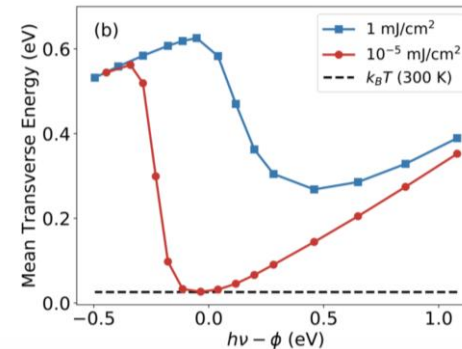
Low-electron-affinity semiconductor photocathodes

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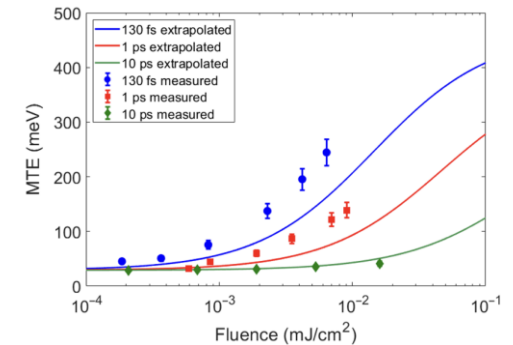
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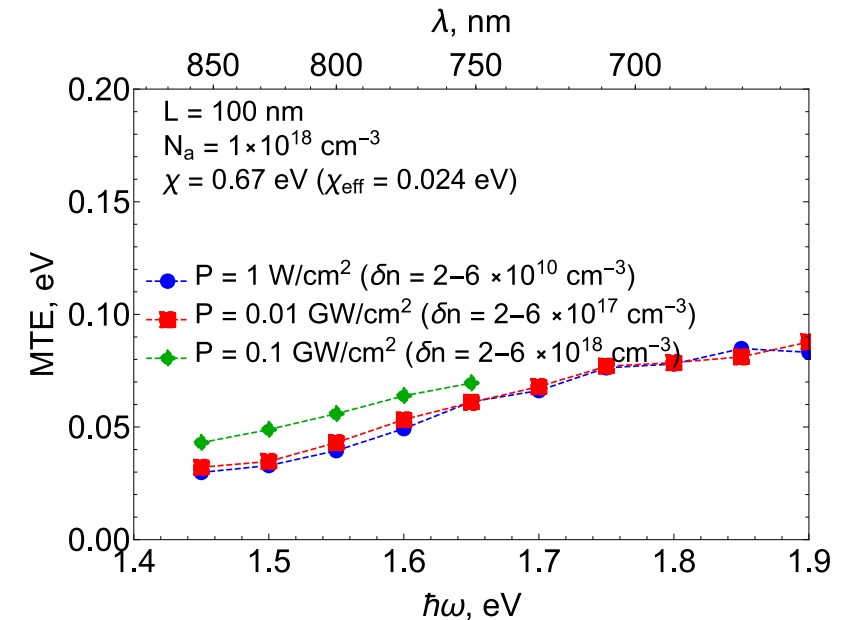
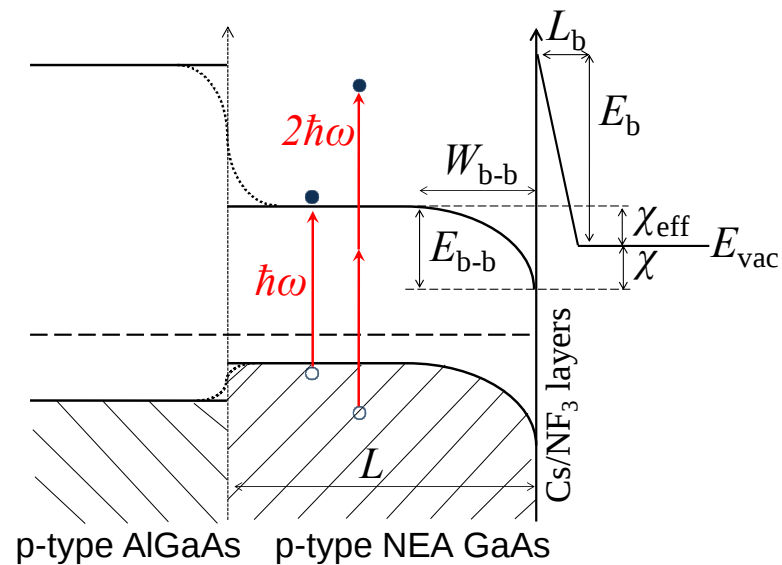
- Multi-photon absorption limits MTE!



Bae et al. J. App. Phys. **124**, 244903 (2018)



Knill et al., Phys. Rev. Accel. Beams **26**, 093401 (2023)



Low-electron-affinity semiconducting photocathodes are better candidates to operate under high laser fluences.

Cesium-antimonide photocathodes

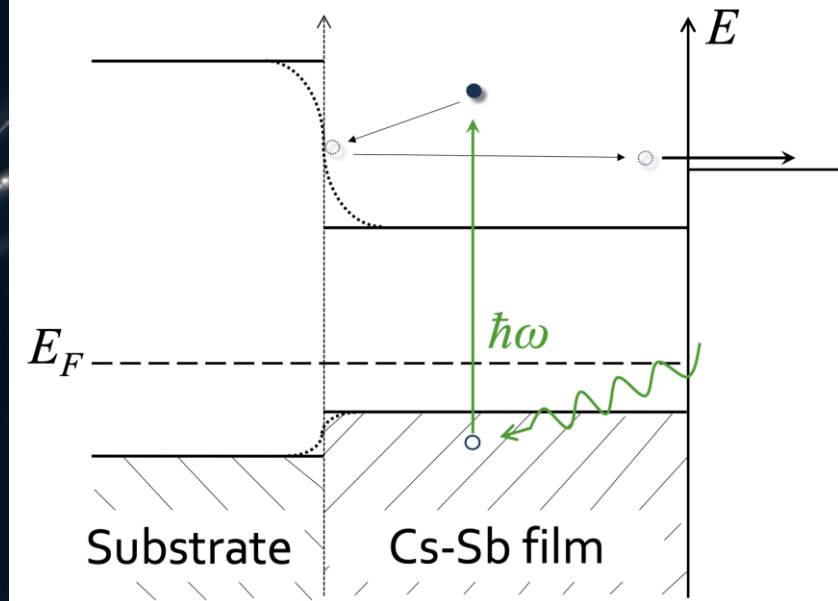
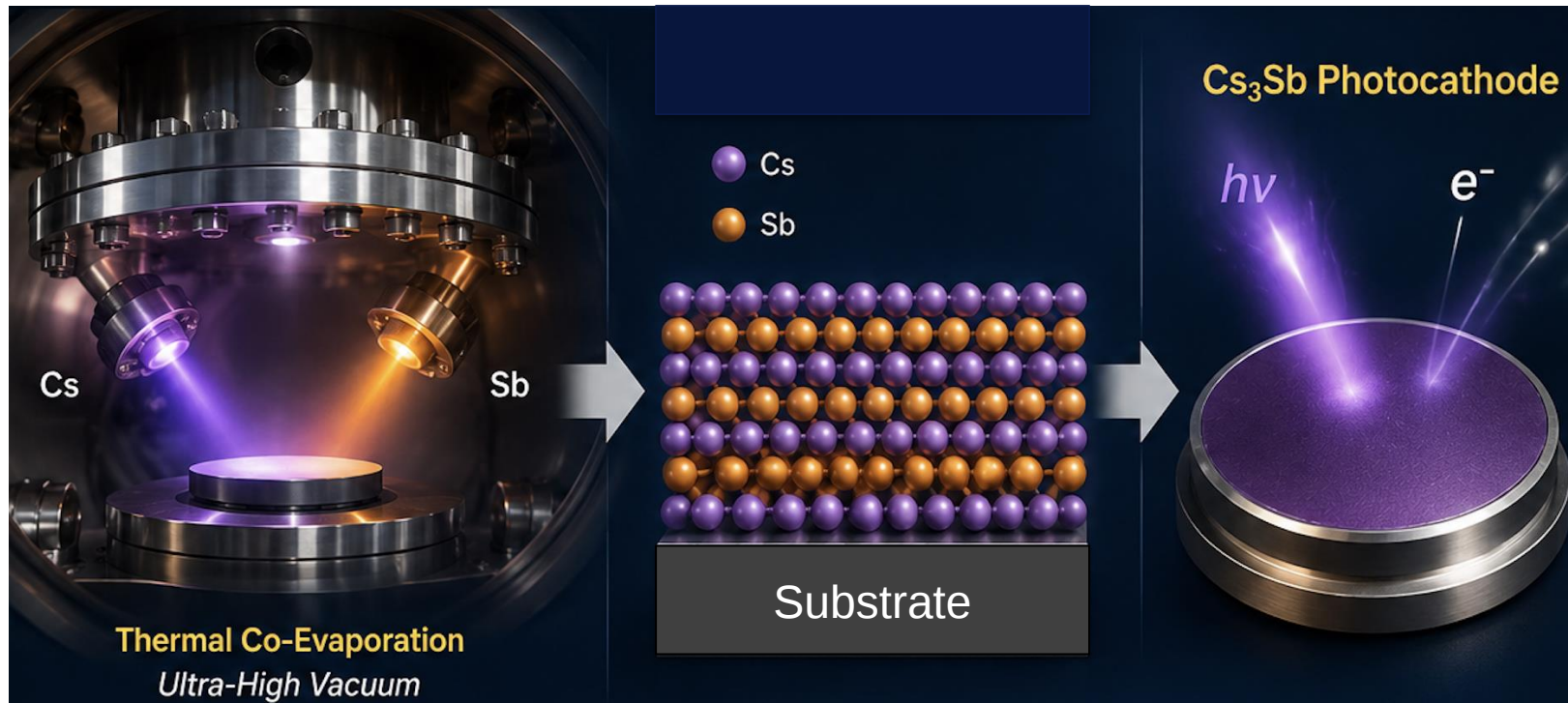
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Cesium-antimonide photocathodes (Cs-Sb):

- promising candidates for generating extremely bright electron beams for XFELs, UED, and UEM.
- can be easily deposited through thermal evaporation at moderate temperatures.
- thin films (several 10s of nm).



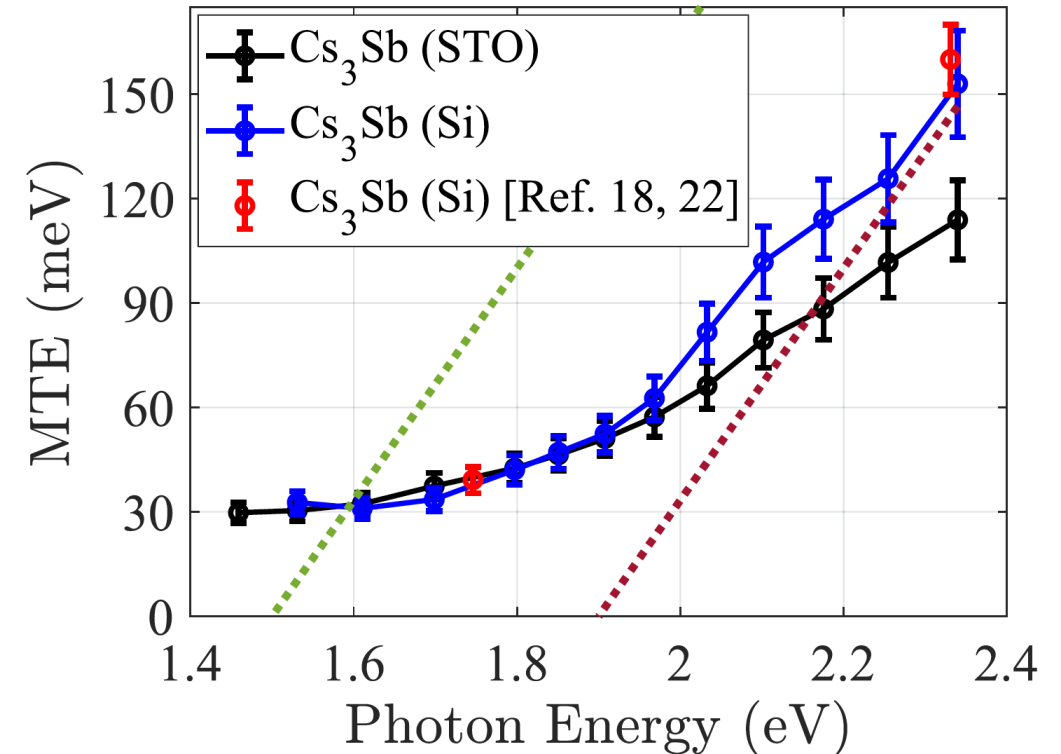
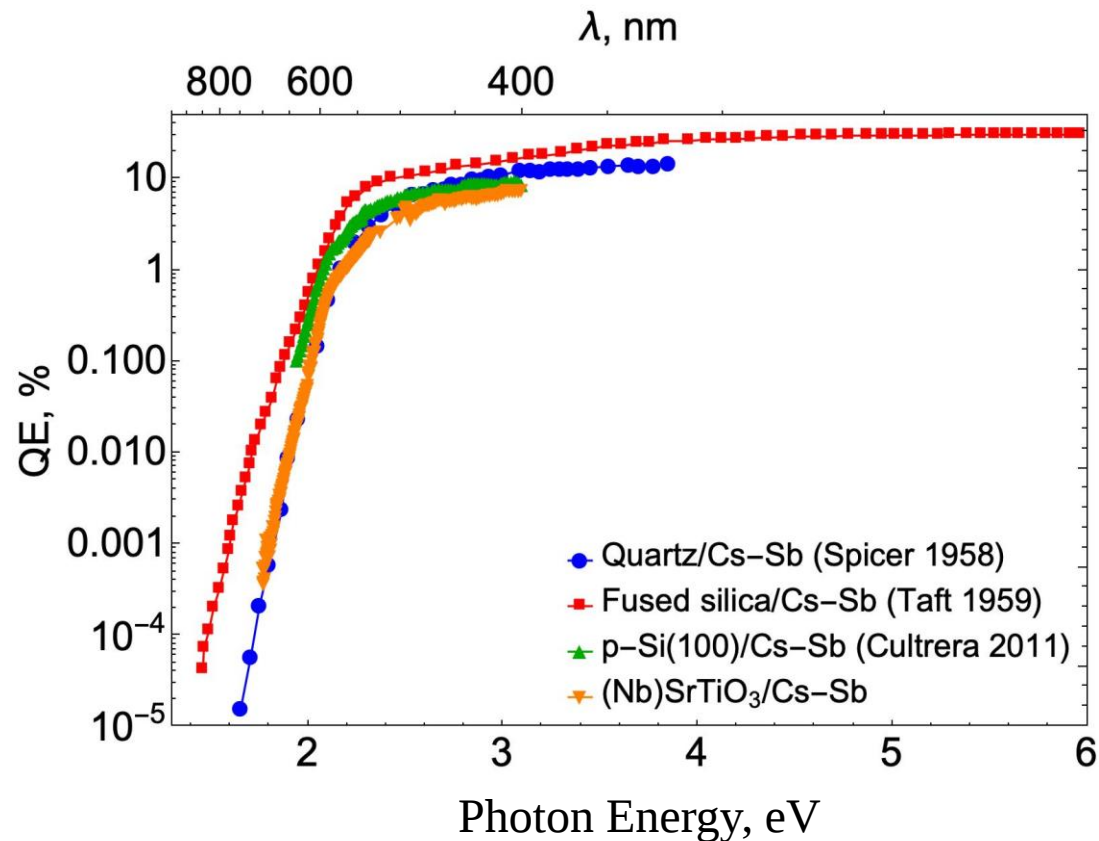
Cesium-antimonide photocathodes

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- Operational photon energy affects MTE!



A. Kachwala, P. Saha, P. Bhattacharyya, E. Montgomery, O. Chubenko, and S. Karkare, Appl. Phys. Lett. 123, 044106 (2023)

Cesium-antimonide photocathodes demonstrate thermal-limit MTE and relatively high QE at photoemission threshold.

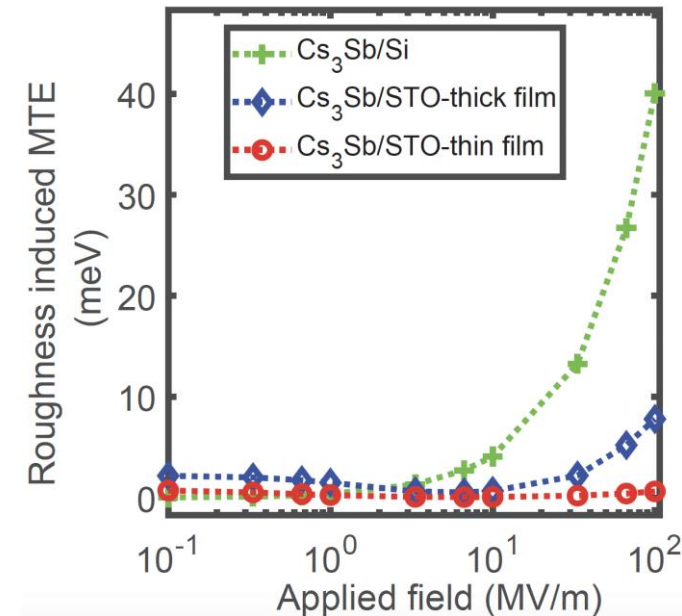
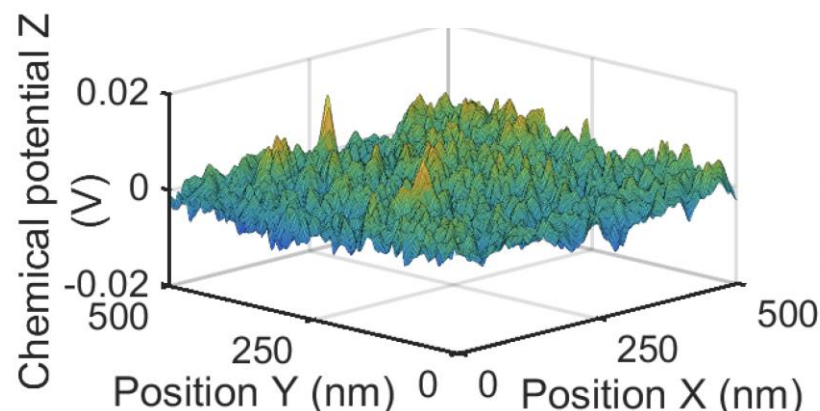
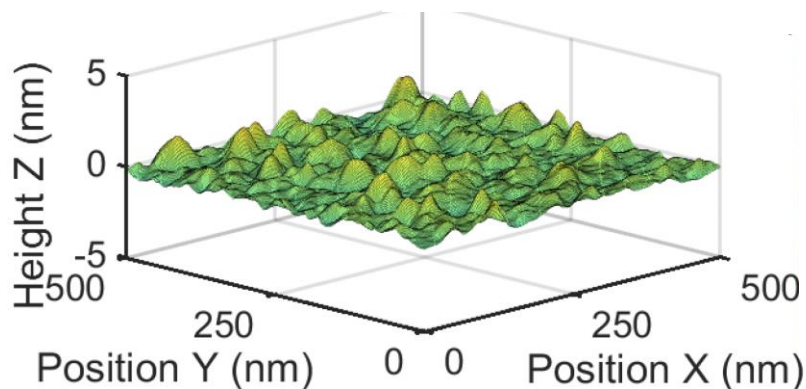
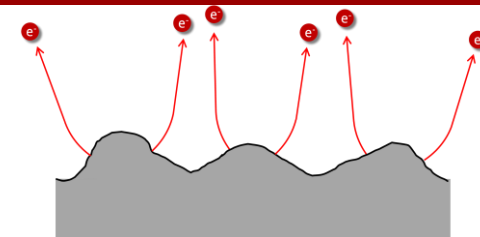
Cesium-antimonide photocathodes

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- Surface roughness and work function variation limit MTE!



Saha, Chubenko et al, Appl. Phys. Lett. **120**, 194102 (2022).

Cesium-antimonide films grown on lattice-matched single crystal strontium titanate (STO) substrates demonstrate roughness-induced MTE < 10 meV even at large applied fields.

Cesium-antimonide photocathodes

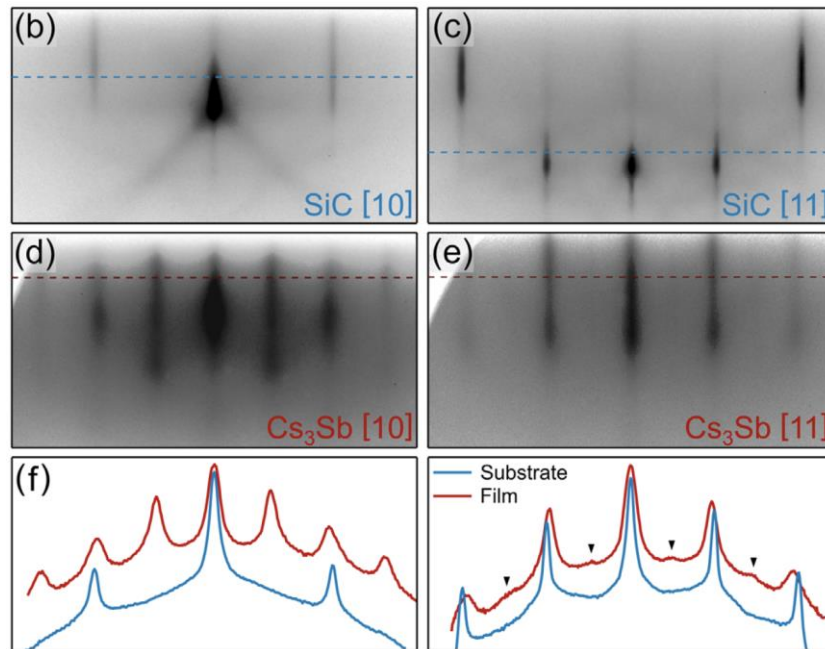
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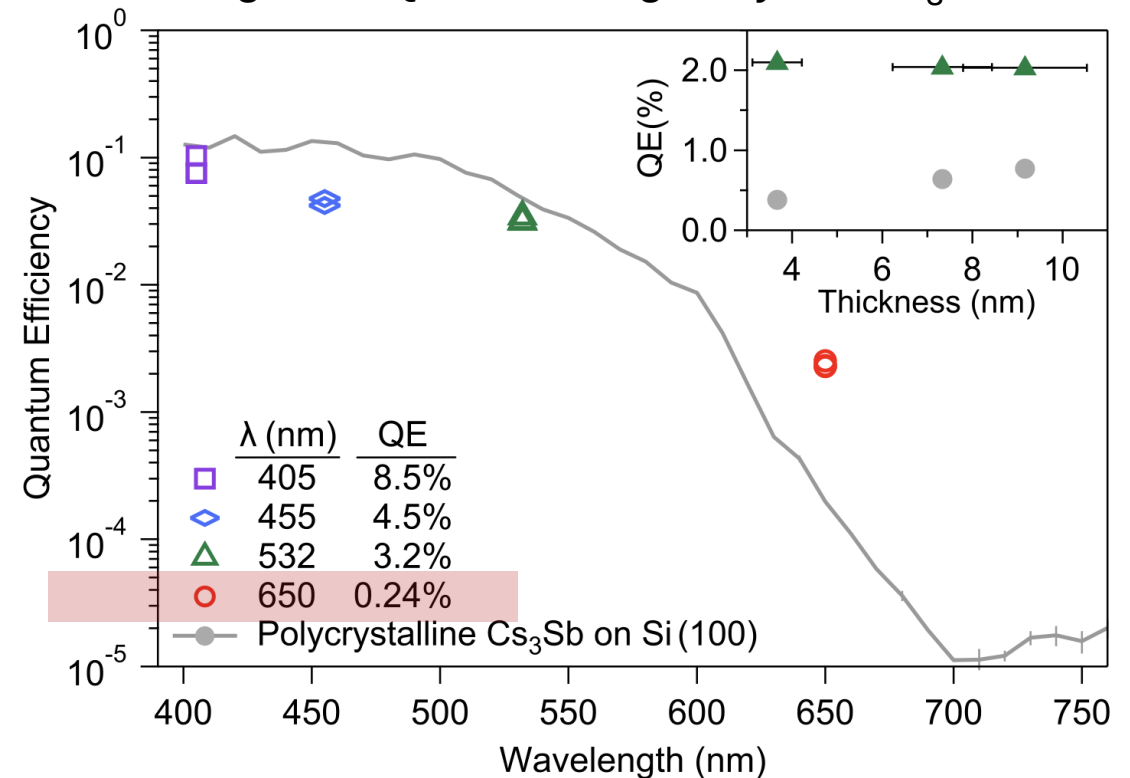
- Disordered crystal structure limits MTE!

RHEED images of an annealed SiC substrate and a 10 u.c. Cs_3Sb film.



Parzyck et al, Phys. Rev. Lett. **128**, 114801 (2022).

High red QE from single crystal Cs_3Sb



Epitaxial growth of cesium-antimonide films on lattice-matched single crystal SiC substrates.

Cesium-antimonide photocathodes

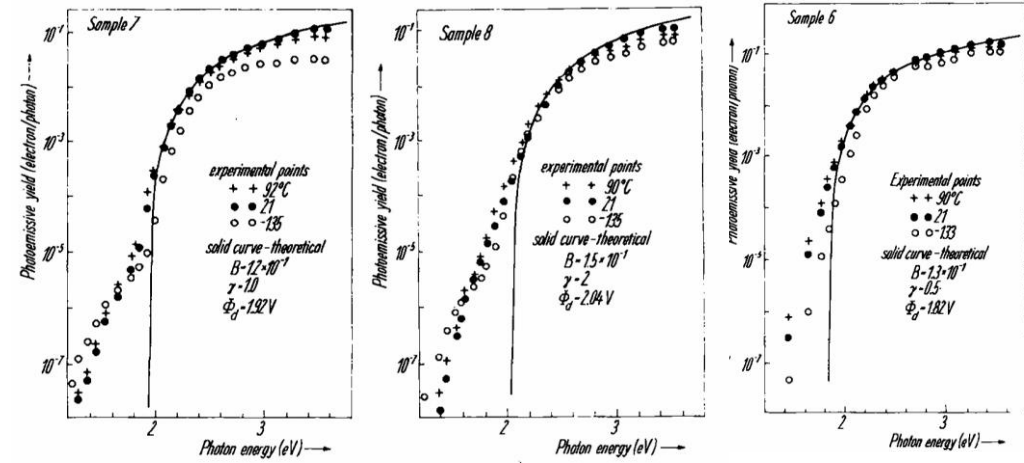
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- Stoichiometry influences photoemission!

Stoichiometric variation

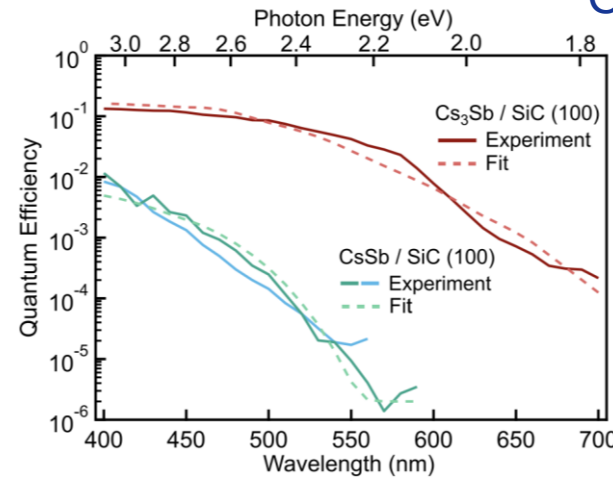


Near Cs_3Sb

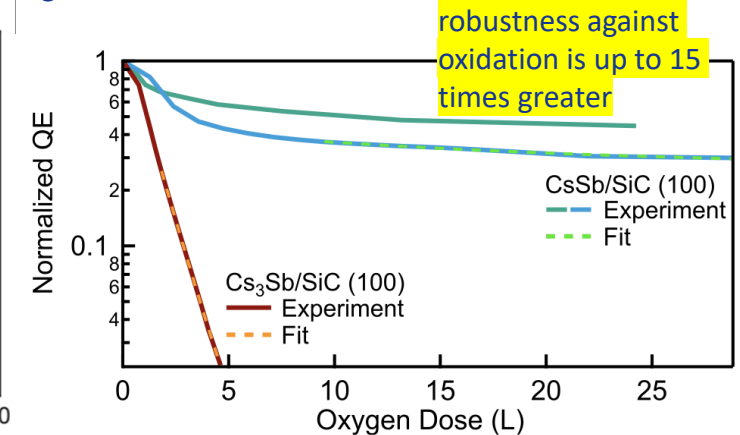
Cs-rich

High yield

Hagino et al, Phys. Stat. Sol. **17**, 609 (1966).

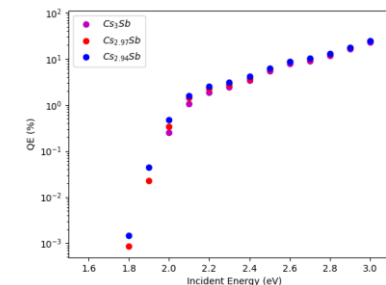
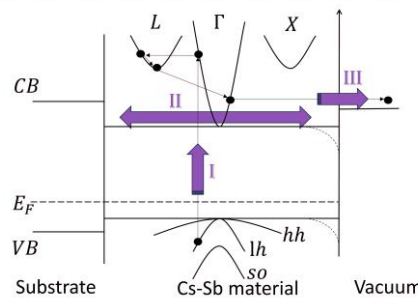


Cs_3Sb vs CsSb



Parzyck et al., APL Mater. **11**, 101125 (2023)

DFT + Monte Carlo
investigation of stoichiometry
influence on photoemission



Daniel Franklin,
T21 (Tuesday)

Detailed modeling and advanced growth and characterization are required to achieve desired stoichiometry.

Testing alkali-antimonide photocathodes in accelerators

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Alkali-antimonide photocathodes (Cs-Sb, Na-K-Sb):

- Low MTE 
- High QE 
- Thin films → prompt response time 
- Robustness + long operational lifetime under realistic photoinjector conditions 

Testing alkali-antimonide photocathodes in accelerators

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Previous experience:

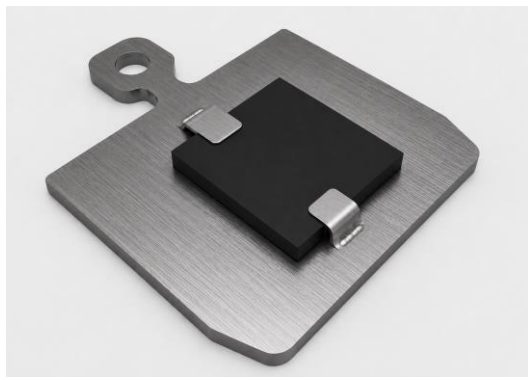
- many tests in DC guns
- very few tests of alkali-antimonides in high field RF/SRF guns
- no RF tests of Cs-Sb films grown on SC substrates.

Complications:

- photocathode sensitivity to vacuum conditions
- incompatibility between photocathode growth systems and photoinjectors



Flag-style sample holder



University labs

Old INFN-style

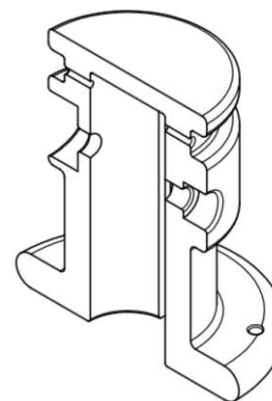


FermiLab, SLAC, UCLA, Cornell

New INFN-style



AWA drive gun



ACT gun



Argonne

Witness gun



Testing alkali antimonide photocathodes at AWA Facility

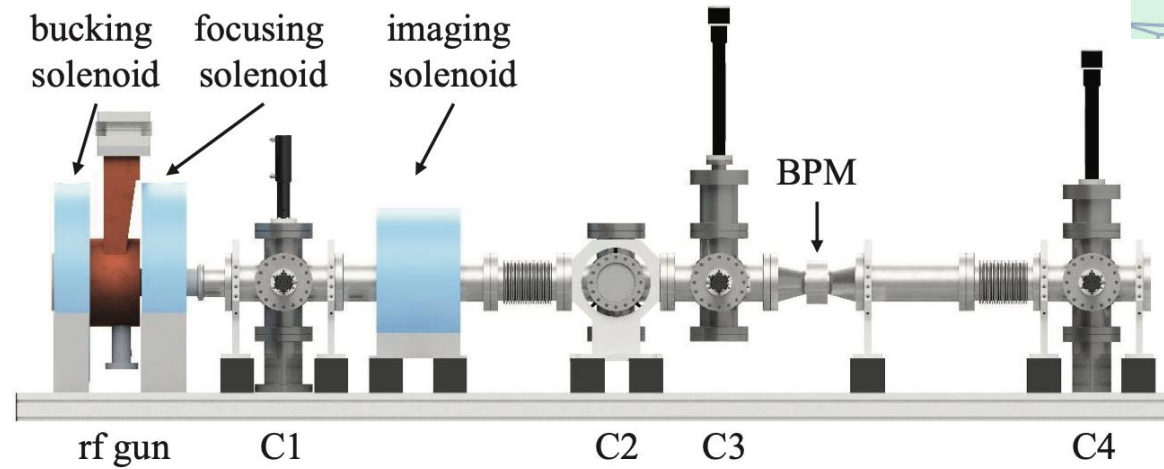
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Argonne Cathode Teststand (ACT):

- L-band 1.3 GHz single-cell photocathode RF gun.
- Emittance measurement capability.
- Close proximity to NIU.
- Currently suitable for testing air-stable materials only.
- Unique plug design.



Shao et al, IPAC 2018



Planned ACT updates:

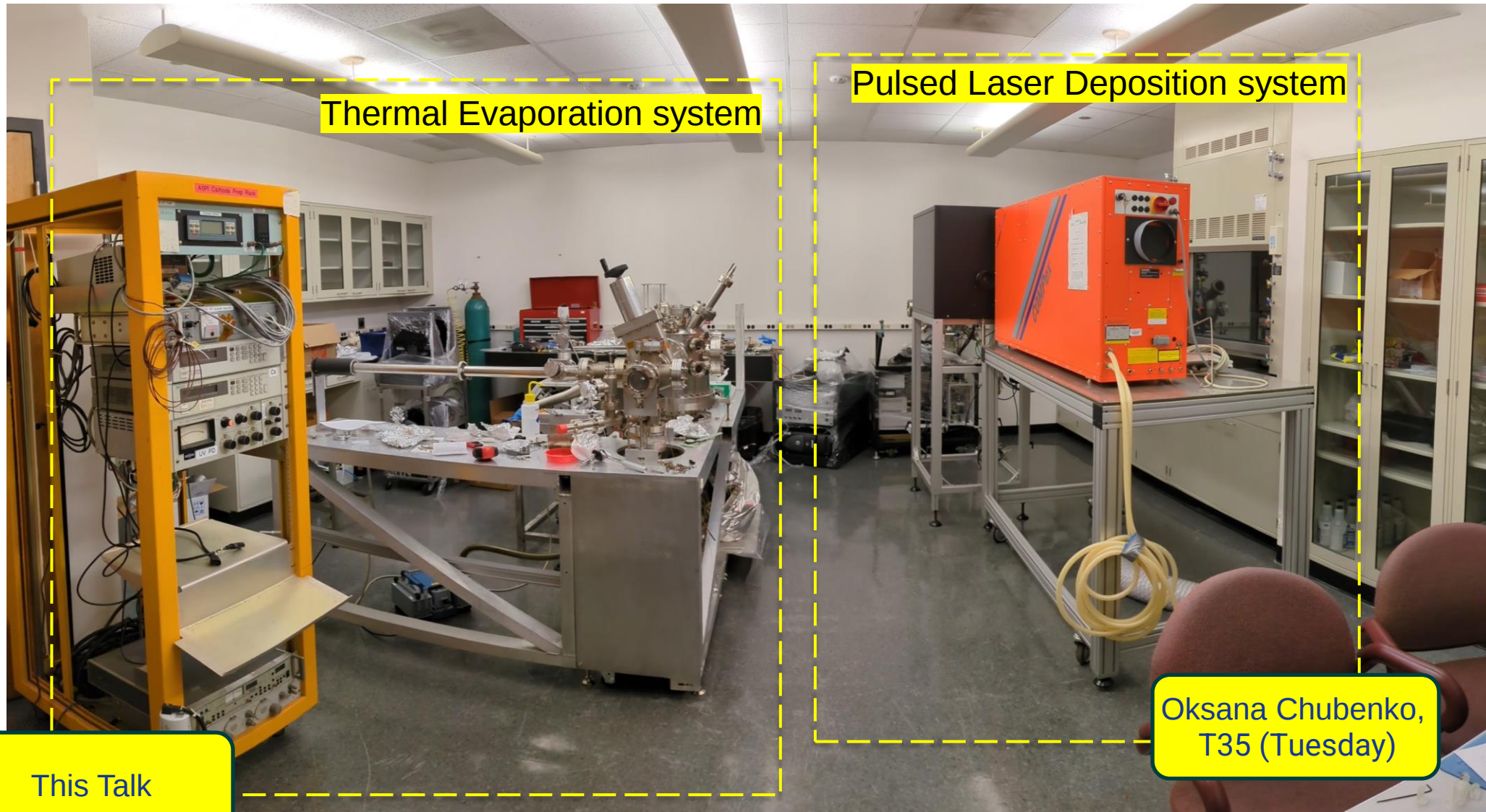
- Update the pump system to achieve $\sim 10^{-10}$ Torr.
- Integrate NIU-compatible photocathode plug suitable for testing different photocathode substrates.
- Possibility of adding the deflecting cavity for photocathode response time measurements.

NIU Photoemission Research Lab

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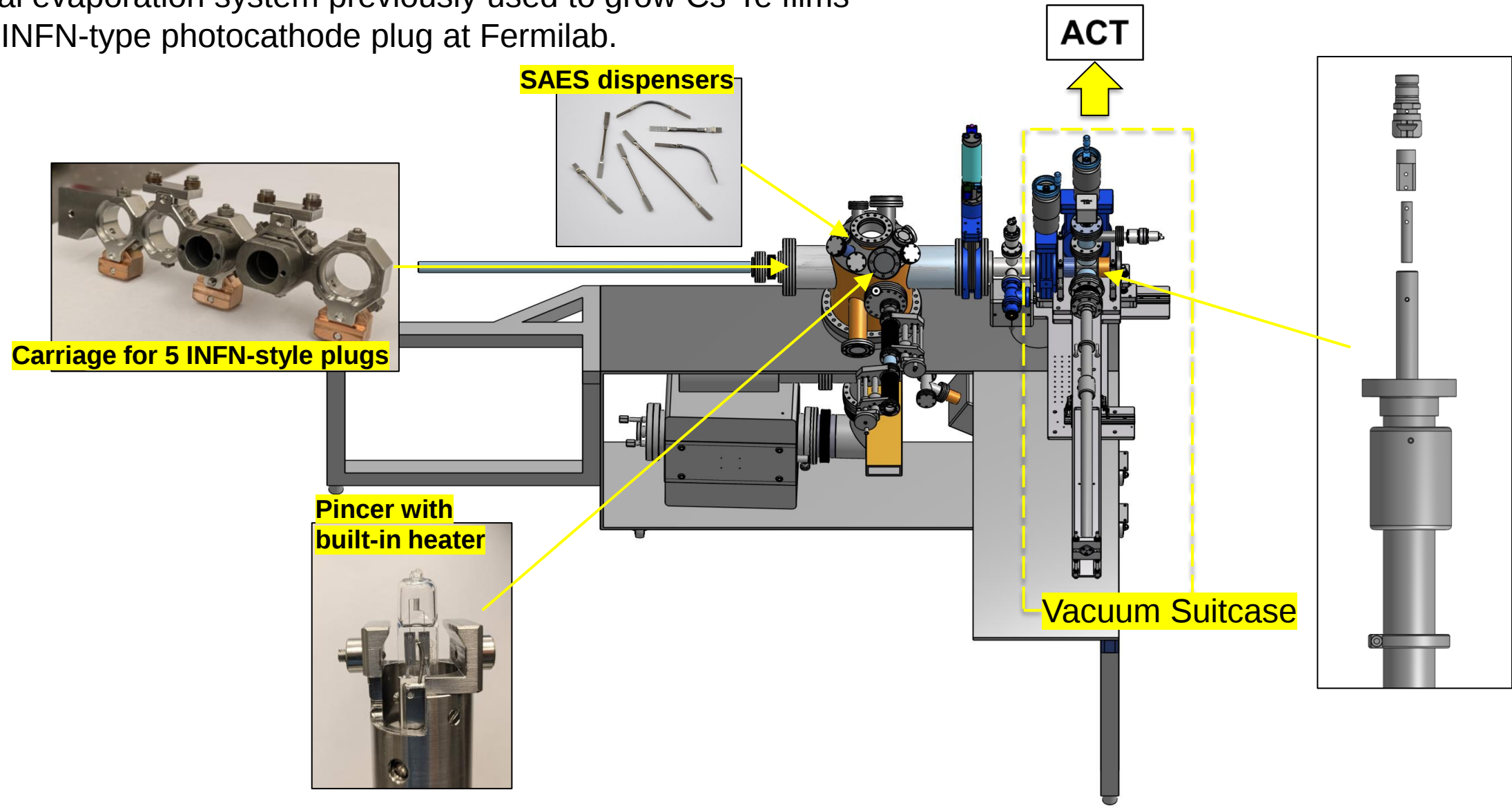
Growth of alkali-antimonide films at NIU

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Thermal evaporation system previously used to grow Cs-Te films on old INFN-type photocathode plug at Fermilab.



Growth of alkali-antimonide films at NIU

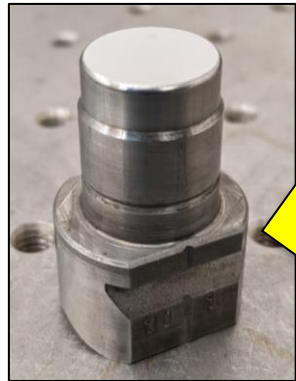
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- New plug enables growth of low-MTE Cs_3Sb films on semiconductor substrates.
- Compatible with ACT

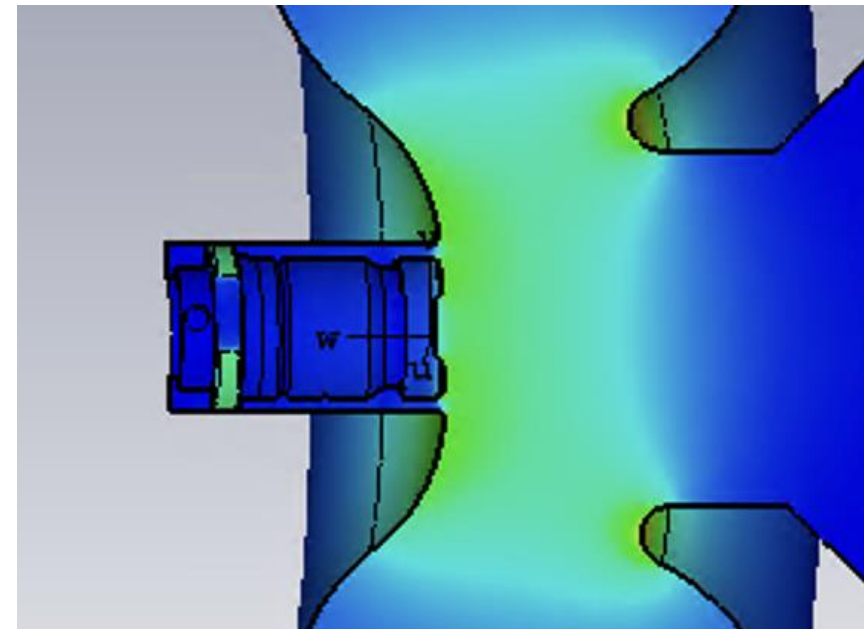
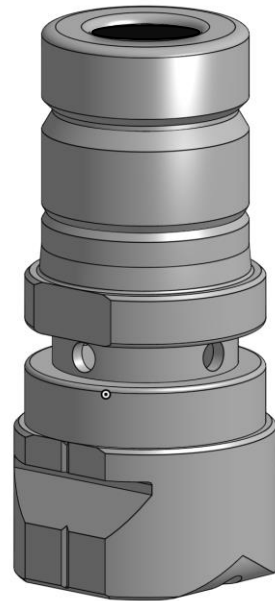
Old INFN-style plug



ACT plug



New NIU plug



NIU plug in ACT

Growth of alkali-antimonide films at NIU

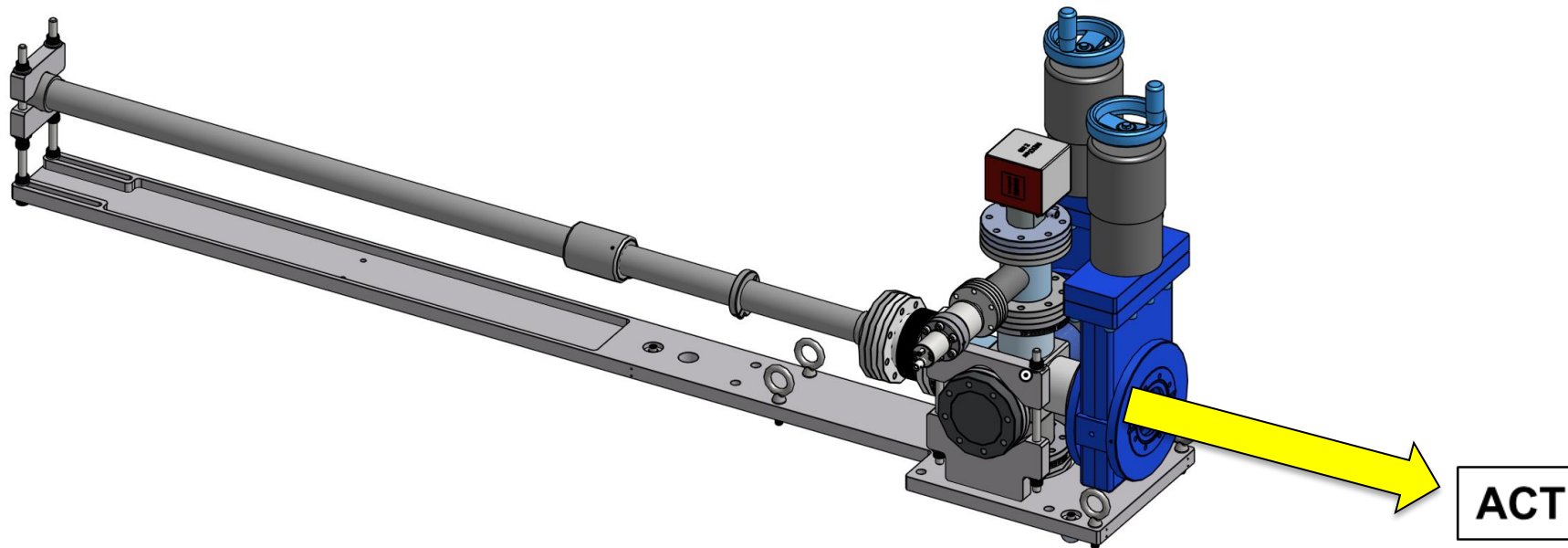
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Developed vacuum suitcase compatible with ACT.

- K. J. Lesker sample transfer device with rolling metal & ceramic bearings for smooth, low friction actuation, with minimal outgassing.
- NEX Torr® UHV pump.
- Two VAT GV's.



Growth of alkali-antimonide films at NIU

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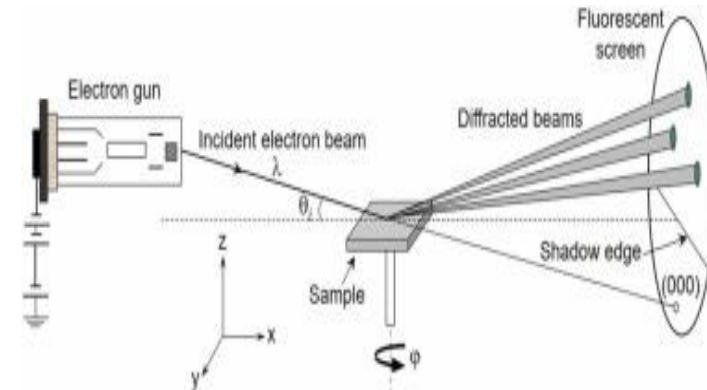
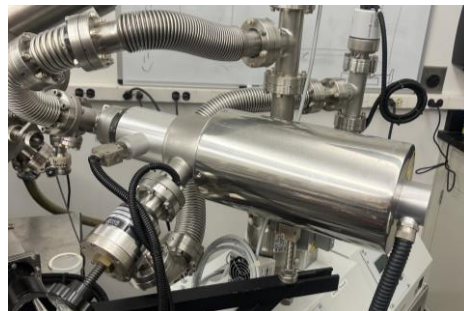
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Further system upgrades:

- More efficient particle sources



- Implement RHEED system or other mechanism for controlled epitaxial growth of alkali antimonide photocathodes with desired stoichiometry.



Summary

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- High-quality photocathode development through epitaxial growth of atomically smooth crystalline materials.
- Developed experimental setup for the epitaxial growth of alkali antimonide photocathodes on lattice-matched substrates.
- Extensive testing and characterization of photocathodes will be carried out in the L-band RF gun of ACT.
- This project aims to bridge the gap between university-based photocathode R&D and the reliable deployment of high-quality photocathodes in accelerator facilities.

Acknowledgements

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chubenko@niu.edu

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